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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/986,896	11/13/2001	Mitsushi Ikeda	216074US2TTCRD	6151

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EXAMINER

YE, LIN

ART UNIT	PAPER NUMBER
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2615

DATE MAILED: 07/18/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary

Application No.

09/986,896

Applicant(s)

IKEDA ET AL.

Examiner

Lin Ye

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-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☐ Responsive to communication(s) filed on 03 May 2005.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1-15 is/are pending in the application.
- 4a) Of the above claim(s) 1-4, 6, 7, 9 and 12-14 is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 5, 8, 10, 11 and 15 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☒ The drawing(s) filed on 13 November 2001 is/are: a) ☒ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☒ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☒ All b) ☐ Some * c) ☐ None of:
1. ☒ Certified copies of the priority documents have been received.
 2. ☐ Certified copies of the priority documents have been received in Application No. _____.
 3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|---|---|
| 1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413)
Paper No(s)/Mail Date. _____ |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | 5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152) |
| 3) <input checked="" type="checkbox"/> Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)
Paper No(s)/Mail Date <u>09/22/05</u> | 6) <input type="checkbox"/> Other: _____ |

DETAILED ACTION

Response to Arguments of Election/Restrictions

1. Applicant's election with traverse of the election of Species II, Figure 6 which read on claims 15,8,9,10,11 and 15 in the reply filed on 5/3/05 is acknowledged. The traversal is on the ground(s) that applicants believe a search and examination of the entire application would not place a serious burden on the Examiner. This is not found persuasive because the examiner made a *prima facie* showing of examining burden by pointing out the Species (Figure 1; Figure 6) are patentably distinct from each other. For examples, the Species I Figure 1 (read on claim 1) does not has a common electrode (19) and a power protection diode (50) which comprising two field effect type thin film transistors (TFT 52 and 55) as shown in Species II, Figure 6; and the Species II, Figure 6 (read on claims 5 and 15) does not show a nose corrective circuit (34) which comprising a thin film transistors (TFT 40 and a capacitor (41) as shown in Species I Figure 1.

It also should be noted applicant elects the claim 9 which read on the Species I, Figure 1 because the claim 9 is a dependent claim of claim 1, which includes all of the other limitations of the claim 1, such as a gate drive circuit (31) for switching the thin film transistor (21) and without a common electrode and a field effect type thin film transistor for imaging a signal from the field effect type thin film transistor for pixel switching. For this reason, claim 9 withdrawn from further consideration pursuant to 37 CFR 1.142(b)

The requirement is still deemed proper and is therefore made Final.

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2. Claims 1-4, 6-7, 9 and 12-14 withdrawn from further consideration pursuant to 37 CFR 1.142(b), as being drawn to a nonelected Species Figure 1, there being no allowable generic or linking claim. Applicant timely traversed the restriction (election) requirement filed on 5/3/05.

Claim Rejections - 35 USC § 103

3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.
4. Claims 5 and 11 are rejected under 35 U.S.C. 103(a) as being unpatentable over Tanaka et al. U.S. Patent 6,044,128 in view of Date et al. U.S. Patent 5,973,558.

Referring to claim 5, the Tanaka reference discloses in Figures 1 and 12-14, an X-ray imaging device comprising an X-ray-electric conversion layer (X-ray plane detector 107, see Col. 3, lines 60-67), a common electrode (e.g., photo diode 148 and a pixel capacitor share a common electrode as shown in Figure 12) arranged on one surface of the layer, a plurality of pixel electrodes arranged in an array on the other surface of the layer, a field effect thin film transistor (TFT 144, See Col. 3, lines 9-10) connected to each pixel electrode for pixel switching, including source, drain and gate electrodes, either one of source and drain electrodes being connected to the pixel electrode, the other one being connected to a signal

output line, and the gate electrode being connected to a scanning line (See Col. 3, lines 15-18), and a field effect type thin film transistor (TFT 146, See Col. 3, lines 20-28) for imaging a signal from the field effect type thin film transistor for pixel switching, and the thin film transistor being driven by a driving gate voltage pulse (output from horizontal scanning shift register 152 and vertical scanning shift register 150, See Col. 3, lines 20-26) wherein the X-ray imaging device comprises a correction control circuit (152 & 150) for supplying a gate voltage to the gate electrodes of the thin film transistors (e.g., the thin film transistors 144 & 146 is alternatively controlled ON-OFF by the correction control circuit 152 & 150) used for the X-ray imaging device. However, the Tanaka reference does not explicitly show a detail about the correction control circuit for supplying a gate voltage with a polarity opposite to the gate voltage pulse to at least a part of the gate electrodes of the thin film transistors used for the X-ray imaging device, and the correction control circuit supplies the gate electrode with a gate voltage having a polarity of a direction that makes the mean value of the driver gate pulses at operating period be zero or reduced, during non-image reading period of the X-ray imaging device.

The Date reference teaches in Figure 3, a imaging device comprising a correction control circuit supplying a gate voltage (standby control signal STBY) with a polarity opposite to the gate voltage pulse to at least a part of the gate electrodes of a thin film transistors (e.g., 202 and 201) used for the X-ray imaging device, and the correction control circuit supplies the gate electrode with a gate voltage (gate potential) having a polarity of a direction that makes the mean value of the driver gate pulses at operating period be zero or reduced, during non-image reading period (the period of the thin film transistors turned off) of the imaging

device (See Col. 9, lines 23-38). The Date reference is evidenced that one of ordinary skill in the art at the time to see more advantages for the solid state imaging device supplying a gate voltage pulse with a polarity opposite to the gate voltage pulse to at least a part of the gate electrodes of a thin film transistors so that easily providing a switch function to the thin film transistors for controlling imaging reading. For that reason, it would have been obvious one having ordinary skill in the art at the time of the invention was made to modify the X-ray imaging device of the Tanaka ('128) by providing a gate voltage with a polarity opposite to the gate voltage pulse to at least a part of the gate electrodes of the thin film transistors used for the X-ray imaging device, and the correction control circuit supplies the gate electrode with a gate voltage having a polarity of a direction that makes the mean value of the driver gate pulses at operating period be zero or reduced, during non-image reading period of the X-ray imaging device as taught by Date ('558).

Referring to claim 11, the Tanaka reference discloses wherein the thin film transistor is made of amorphous silicon (See Col. 2, lines 25-28).

5. Claims 8 and 15 are rejected under 35 U.S.C. 103(a) as being unpatentable over Tanaka et al. U.S. Patent 6,044,128 in view of Date et al. U.S. Patent 5,973,558 and Kamimura U.S. Patent 6,081,015.

Referring to claims 8 and 15, the Tanaka and Date references disclose all subject matter as discussed with respected to claim 5, and the Tanaka reference discloses wherein the device comprises a protection diode (MIM Structure 9 as a protective diode, see Col. 7, lines 39-50, Col. 11, lines 37-42 and Figure s 2A-4) limiting the voltage of the pixel electrode (7) not to

exceed the protection voltage, a power source (148, see Col. 3, lines 14-15 and Figure 12) supplying a predetermined voltage to the common electrode (49, see Col. 7, lines 31-33), a gate drive circuit switching the thin film transistor (TFT 5, See Col. 7, lines 25-30) by supplying a driver gate voltage pulse to the gate electrode at operating period, and a power circuit (as shown in Figure 2A) for the protection diode connected to the protection diode (9). However, the Tanaka reference does not explicitly show the protection diode composed of a field effect type thin film transistor and the power circuit supplying a limited voltage lower than the voltage of the power source thereto, wherein the power source for the protection diode supplies a voltage lower than the limited voltage at operating period to the protection diode at non-operating period.

The Kamimura reference teaches in Figures 1A-1B, a imaging device comprising a protection diode (transistor H11, H12 and H13) are constituted of MOS thin film transistor, bipolar transistors or diodes (See Col. 55-65); and the power circuit (terminal T2 has voltage 0-5V) supplying a limited voltage (the electric strength of the gate C1, see Col. 8, lines 1-14) lower than the voltage of the power source (terminal T1 has -9V-0-15V) thereto, wherein the power source (T1) for the protection diode (H13 and H12) supplies a voltage lower than the limited voltage at operating period to the protection diode at non-operating period (e.g., the both power circuit T2 and power source T1 supply a voltage should lower than the electric strength of the gate C1 for prevent a voltage higher than the electrical strength of the gate C1 from being destroyed, See Col. 8, lines 19-34). The Date reference is evidenced that one of ordinary skill in the art at the time to see more advantages for the solid state imaging device having more flexible options to use any types transistors, diode or structures as a power

protection circuit; and the power circuit supplying a limited voltage lower than the voltage of the power source thereto, wherein the power source for the protection diode supplies a voltage lower than the limited voltage at operating period to the protection diode at non-operating period, so that significantly improving a power protective function for the image device (See Col. 4, lines 45-55). For that reason, it would have been obvious one having ordinary skill in the art at the time of the invention was made to modify the X-ray imaging device of the Tanaka ('128) by providing the protection diode composed of a field effect type thin film transistor and the power circuit supplying a limited voltage lower than the voltage of the power source thereto, wherein the power source for the protection diode supplies a voltage lower than the limited voltage at operating period to the protection diode at non-operating period as taught by Kamimura ('015).

6. Claim 10 rejected under 35 U.S.C. 103(a) as being unpatentable over Tanaka et al. U.S. Patent 6,044,128 in view of Date et al. U.S. Patent 5,973,558 and Kaifu U.S. Patent 6,448,561.

Referring to claim 10, the Tanaka and Date references disclose all subject matter as discussed with respect to claim 5, except that the Tanaka reference does not explicitly show a detail that the signal of the pixel electrode is picked up at every frame comprising an X-ray radiating period and a blanking period of non-radiating, and the non-operating period corresponds to the blanking period.

The Kaifu reference teaches in Figures 10A-10D, a x-ray imaging device comprising a control circuit (4, see Col. 7, lines 30-37) for controlling the signal of the pixel electrode is

picked up at every frame comprising an X-ray radiating period (Figure 10B is the X-ray emission timing) and a blanking period of non-radiating, and the non-operating period corresponds to the blanking period (the exposure period of x-ray imaging device as operating period is corresponding to the X-ray emission period, see Col. 8, lines 25-45). The Kaifu reference is evidenced that one of ordinary skill in the art at the time to see more advantages for the x-ray imaging device having the control circuit to control the signal of the pixel electrode is picked up at every frame comprising an X-ray radiating period and a blanking period of non-radiating, and the non-operating period corresponds to the blanking period so that the image device has high in reliability, and good in operability (See Col. 4, lines 17-29). For that reason, it would have been obvious one having ordinary skill in the art at the time of the invention was made to modify the X-ray imaging device of the Tanaka ('128) by providing the control circuit to control the signal of the pixel electrode is picked up at every frame comprising an X-ray radiating period and a blanking period of non-radiating, and the non-operating period corresponds to the blanking period as taught by Kaifu ('561).

Conclusion

7. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.
 - a. Tsutsumi et al. U.S. 6,713,748 discloses a x-ray imaging device including a protection diode composed of a field effect type thin film transistor as shown in Figure 8.

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- b. Brauers et al. U.S. 6,363,135 discloses a sensor which includes a reference electrode as well as a plurality of sensor.
8. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Lin Ye whose telephone number is (571) 272-7372. The examiner can normally be reached on Mon-Fri 8:00AM-5:00PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, David L. Ometz can be reached on (571) 272-7593. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306 (On July 15, 2005, the fax number will change to 571-273-8300)

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).



Lin Ye
Examiner
Art Unit 2615

July 13, 2005